



Substitute for form 1449/PTO

# **Information Disclosure Statement By Applicant** (Use as many sheets as necessary)

Application Number	10/788,857
Filing Date:	February 26, 2004
First Named Inventor:	Chao I. WU
Art Unit:	2824
Examiner Name:	N. Nguyen
Attorney Docket Number:	MXICP031

1 of 1

## **U.S. Patent Documents**

Examiner Initial	Cite No.	Document No.	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, where Relevant Passages or Relevant Figures Appear
NW	A	6,011,725	1/2000	Eitan	
NW	B	6,487,114	11/2002	Jong et al.	
	C				
	D				
	E				
	F				
	G				
	H				
	I				
	J				
	K				

## **Foreign Patent Documents**

Examiner Initial	Cite No.	Foreign Patent Document No.	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, where Relevant Passages or Relevant Figures Appear	Translation
	L					YES NO
	M					
	N					
	O					
	P					
	Q					

## **Non Patent Literature Documents**

Examiner Initial	Cite No.	Include name of author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.
NW	R	T. Y. CHAN et al., "A True Single-Transistor Oxide-Nitride-Oxide EEPROM Device," IEEE Electron Device Letters, Vol. EDL-8, No. 3, March 1987, pp. 93-95
	S	
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	W	

Examiner Signature	Nam Nguyen	Date Considered	2/24/06
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Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.